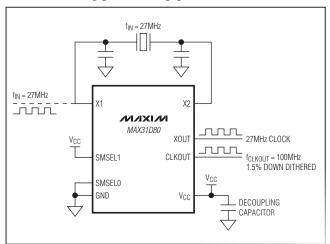


General Description

The MAX31C80/MAX31D80 are spread-spectrum clock generators that contain a phase-locked loop (PLL) that generates a 2MHz to 134MHz clock from an input clock or crystal. The PLL can provide a spread-spectrum down-dithered (MAX31D80) or center-dithered (MAX31C80) frequency-modulated clock. The devices also buffer the incoming clock and provide this output on a separate pin.

The MAX318C80/MAX31D80 are provided in a 10-pin TDFN package and operate over a full -40°C to +125°C automotive temperature range. Devices can be factory programmed for multiple combinations of input and output frequencies (see the Ordering Information table). A low-cost, low-frequency crystal can be used at the input to generate frequencies up to 134MHz.

Typical Application Circuit



Features

- ♦ 2MHz to 134MHz Spread-Spectrum Clock Generator
- ♦ Input Can Be Either an 8MHz to 34MHz Crystal or 8MHz to 134MHz Clock
- ♦ Factory-Programmable Output Frequencies in 2MHz to 134MHz Range
- ♦ Low-Cost Crystal at Low Frequency Used to **Generate High Frequencies**
- ♦ On-Board PLL is Capable of Spread-Spectrum **Frequency Modulation**
- ◆ Down- or Center-Dither Spread-Spectrum Frequency Modulation
- User-Configurable Spread-Spectrum Dither Magnitude
- ♦ Low Cycle-to-Cycle Jitter
- ♦ 3.3V Supply Voltage
- ◆ Temperature Range: -40°C to +125°C
- ♦ Small Package: 10-Pin TDFN (3mm x 3mm x 0.8mm)

Applications

Graphics Cards

Set-Top Boxes

Automotive Infotainment

Printers

Ordering Information

PART	TEMP RANGE	DITHER MODE	PIN-PACKAGE
MAX31C80T-xxx+	-40°C to +125°C	Center	10 TDFN-EP*
MAX31C80T-xxx+T	-40°C to +125°C	Center	10 TDFN-EP*
MAX31D80T-xxx+	-40°C to +125°C	Down	10 TDFN-EP*
MAX31D80T-xxx+T	-40°C to +125°C	Down	10 TDFN-EP*

xxx = Factory-programmable output frequency and dither rate (see the Selector Guide table).

Selector Guide appears at end of data sheet.

/U/IXI/U

Maxim Integrated Products 1

⁺Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

^{*}EP = Exposed pad.

ABSOLUTE MAXIMUM RATINGS

Voltage Range on Vcc Relative to GND.....-0.3V to +4.3V Voltage Range on Any Other Pin Relative to GND....-0.3V to (Vcc + 0.3V)* Continuous Power Dissipation (TA = +70°C) 10-Pin TDFN (derate 24.4mW/°C above +70°C).....1951.2mW

Storage Temperature Range......-55°C to +135°C Lead Temperature (soldering, 10s)....+300°C Soldering Temperature (reflow)...+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

 $(T_A = -40^{\circ}C \text{ to } +125^{\circ}C.)$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	Vcc		3.0	3.3	3.6	V
Input Logic 0 (SMSEL0 and SMSEL1)	VIL		-0.3		0.25 x Vcc	V
Input Logic 1 (SMSEL0 and SMSEL1)	VIH		0.75 x VCC		V _{CC} +	V
Input Logic Unconnected (SMSEL0 and SMSEL1)	VIF	Limits are in case user wants to force voltage instead of unconnecting this pin	0.4 x VCC		0.55 x VCC	V
Input Logic 0 for X1	VIL:X1		-0.3		0.3 x VCC	V
Input Logic 1 for X1	V _{IH:X1}		0.7 x VCC		V _{CC} +	V
XOUT Load	CL:XOUT				15	рF
CLKOUT Load	CL:CLKOUT	$2MHz \le f_{CLKOUT} < 67MHz$ $67MHz \le f_{CLKOUT} < 101MHz$ $101MHz \le f_{CLKOUT} \le 134MHz$			15 10 7	pF
Crystal Frequency	fIN		8		34	MHz
Clock Input Frequency	fIN		8		134	MHz
Crystal ESR	X _{ESR}				90	Ω
Clock Input Duty Cycle	fINDC		40		60	%
Crystal Parallel Load Capacitance	CCL				18	pF

MIXIM

^{*}Not to exceed +4.3V.

DC ELECTRICAL CHARACTERISTICS

 $(3.0V \le VCC \le 3.6V$, TA = -40°C to +125°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Current	IDD	$f_{IN} = 27MHz$, $f_{CLKOUT} = 100MHz$, down dithered, $C_L = 10pF$		22		mA
Input Leakage (SMSEL0 and SMSEL1)	lıL	SMSEL_ = GND or VCC			±15	μА
Low-Level Output Voltage (XOUT and CLKOUT)	VoL	IOL = 10mA			0.2	V
High-Level Output Voltage (XOUT and CLKOUT)	VoH	I _{OH} = -10mA	Vcc - 0.2			V
Input Capacitance (X1 and X2)	CIN			5		pF

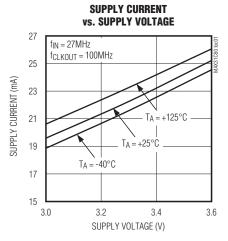
AC ELECTRICAL CHARACTERISTICS

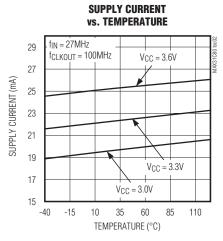
 $(3.0V \le V_{CC} \le 3.6V$, TA = -40°C to +125°C, unless otherwise noted.)

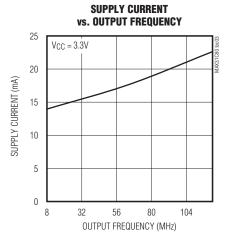
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
CLKOUT Duty Cycle	fCLKOUT:DC	CL:CLKOUT = 7pF	40		60	
XOUT Duty Cycle	fXOUT:DC	C _{L:XOUT} = 7pF, T _A = +25°C, V _{CC} = 3.3V	40		60	%
Rise Time	t _R	CL:CLKOUT = 7pF		1.6		ns
Fall Time	tF	CL:CLKOUT = 7pF		1.6		ns
Dither Rate Range	fDR	Factory programmable	20		40	kHz
Dither Rate Accuracy			-4		+4	%
Peak Cycle-to-Cycle Jitter	tJ	CLKOUT = 100MHz, 10,000 cycles, T _A = +25°C		75		ps
Power-Up Time	tpup	V _{CC} valid to output active, $T_A = +25$ °C, $V_{CC} = 3.3$ V		1		ms

Typical Operating Characteristics

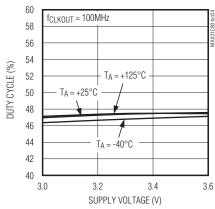
 $(V_{CC} = +3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$



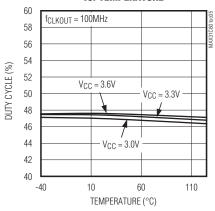




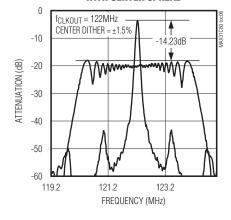
DUTY CYCLE vs. Supply voltage



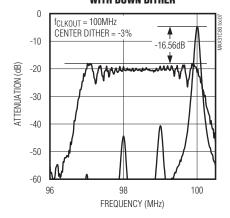




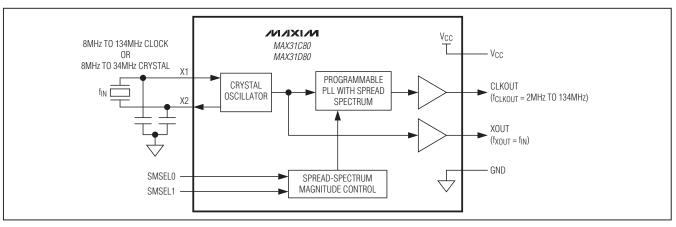
FREQUENCY SPECTRUM AT 122MHz WITH CENTER SPREAD



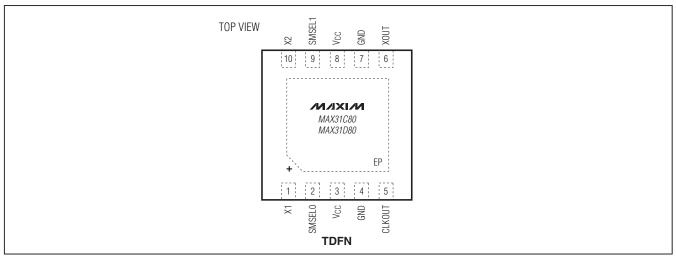
FREQUENCY SPECTRUM AT 100MHz WITH DOWN DITHER



Block Diagram



Pin Configuration



Pin Description

PIN	NAME	FUNCTION
1	X1	Crystal Drive/Clock Input. A crystal with the proper loading is connected across X1 and X2. Instead of a crystal, a clock can be applied at the X1 input. If no clock or crystal is present, then no clock is output at either XOUT or CLKOUT.
2, 9	SMSEL0, SMSEL1	Spread-Spectrum Magnitude Select. These are three-state digital inputs to determine the spread-spectrum magnitude. Tables 1 and 2 provide details for configuration of these pins for down and center dither, respectively.

PIN	NAME	FUNCTION
3, 8	Vcc	Supply Voltage
4, 7	GND	Ground
5	CLKOUT	Clock Output. Spread-spectrum-capable digital output clock from the PLL.
6	XOUT	Crystal Buffered Output. Buffered digital output of the input crystal or clock.
10	X2	Crystal Drive Output. A crystal with the proper loading is connected across X1 and X2. If a clock is applied at the X1 input, then X2 should be left open circuit.
_	EP	Exposed Pad. Connect to GND.

_Detailed Description

The MAX31C80/MAX31D80 modulate an input clock to generate a center-dithered or down-dithered spread-spectrum output. An 8MHz to 27MHz crystal or 8MHz to 134MHz oscillator input is applied to the device. An internal PLL dithers the output clock at a user-selectable magnitude to produce a down-dithered or center-dithered output clock. The output clock's frequency is programmable from 2MHz to 134MHz. The devices also

buffer the incoming clock and provide this output on a separate pin.

Spread-Spectrum Dither Magnitude

The MAX31D80 can generate down-dithered magnitudes up to -3%. The MAX31C80 can generate center-dithered magnitudes up to $\leq 1.5\%$. The desired magnitude is selected using the input pins SMSEL1 and SMSEL0 as shown in Tables 1 and 2. A power cycle is required after each change of the dither magnitude for the changes to take effect.

Table 1. Spread-Spectrum Mode and Magnitude Select (for Down Dither)

SMSEL1	SMSEL0	SPREAD-SPECTRUM MAGNITUDE SELECTED (%)	SPREAD-SPECTRUM DITHER MODE SELECTED		
0	0	Spread-Spec	Spread-Spectrum Disabled		
0	Unconnected	0 to -0.25			
0	1	0 to -0.375			
Unconnected	0	0 to -0.5			
Unconnected	Unconnected	0 to -0.75	Davin Dithar		
Unconnected	1	0 to -1.0	Down Dither		
1	0	0 to -1.5			
1	Unconnected	0 to -2.0			
1	1	0 to -3.0			

Table 2. Spread-Spectrum Mode and Magnitude Select (for Center Dither)

SMSEL1	SMSEL0	SPREAD-SPECTRUM MAGNITUDE SELECTED (%)	SPREAD-SPECTRUM DITHER MODE SELECTED
0	0	Spread-Spec	trum Disabled
0	Unconnected	-0.25 to +0.25	
0	1	-0.375 to +0.375	
Unconnected	0	-0.5 to +0.5	
Unconnected	Unconnected	-0.75 to +0.75	Contar Dithor
Unconnected	1	-1.0 to +1.0	Center Dither
1	0	-1.5 to +1.5	
1	Unconnected	N/A	
1	1	N/A	

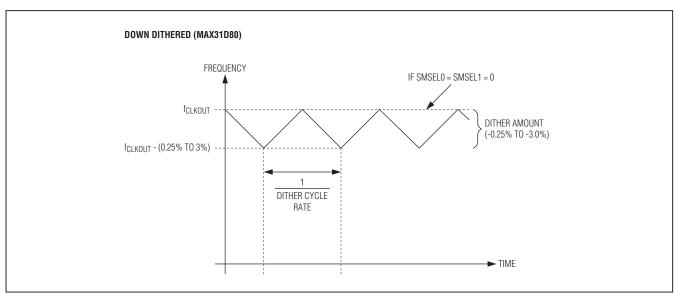


Figure 1. Spread-Spectrum Frequency Modulation (Down Dithered)

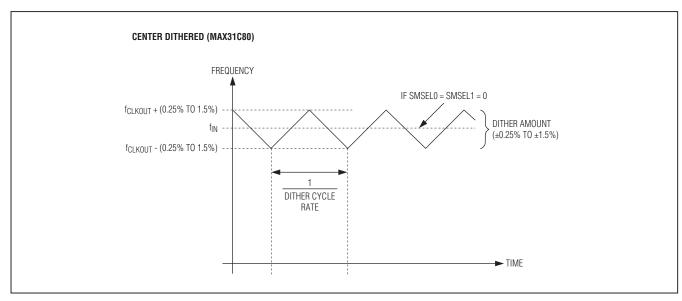


Figure 2. Spread-Spectrum Frequency Modulation (Center Dithered)

MAX31C80/MAX31D80

Spread-Spectrum Clock Generators

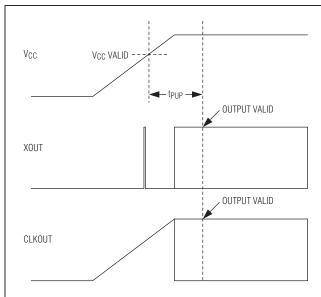


Figure 3. Power-Up Timing

Factory Programmability

The MAX31C80/MAX31D80 can provide a variety of frequencies, which are available to users by ordering the device according to specifications listed in the *Selector Guide* table.

Email the factory at <u>custom.oscillators@maxim-ic.com</u> to obtain custom output frequencies for specific input frequencies not mentioned in the *Selector Guide* table.

_Applications Information

Power-Supply Decoupling

To achieve best results, it is highly recommended that a decoupling capacitor be used on the IC power-supply pins. Typical values of decoupling capacitors are $0.01\mu F$ and $0.1\mu F$. Use a high-quality, ceramic, surface-mount capacitor and mount it as close as possible to the VCC pins of the IC to minimize lead inductance.

Selector Guide

PART	INPUT FREQUENCY (MHz)	OUTPUT FREQUENCY (MHz)	DITHER RATE (kHz)	DITHER TYPE
MAX31C80T-UGQ+	27	100	31.25	Center
MAX31C80T-002+	25	63.05	32.05	Center
MAX31D80T-UGQ+	27	100	31.25	Down
MAX31D80T-003+	12	12	25	Down

⁺Denotes a lead(Pb)-free/RoHS-compliant package.

Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
10 TDFN-EP	T1033+1	<u>21-0137</u>

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	4/10	Initial release	_

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